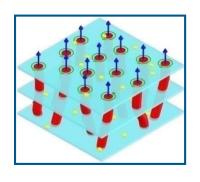


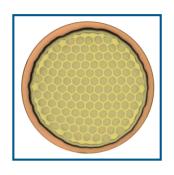


## Superconductivity and its applications

#### Lecture 4



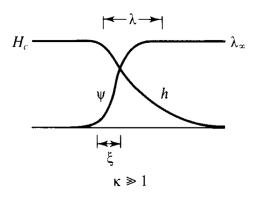
#### **Carmine SENATORE**



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#### Previously, in lecture 3

#### Type-II superconductors: Mixed state and quantized vortices



$$\kappa > \frac{1}{\sqrt{2}} \implies \Delta E < 0$$
wall energy

- Magnetic flux penetrates beyond H<sub>c1</sub>
- Being the wall energy negative, the system prefers to maximize the walls
- The entering flux is fractionated in vortices, each one carrying a flux quantum  $\Phi_0 = \frac{hc}{2e}$

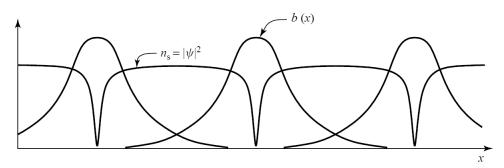
# Previously, in lecture 3 From the Ginzburg-Landau equations

In a type-II superconductor, the critical fields are related to the characteristic lengths

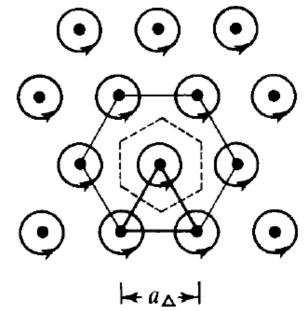
$$H_{c1} = \frac{\Phi_0}{4\pi\lambda^2} \ln \kappa = \frac{H_c}{\sqrt{2}\kappa} \ln \kappa$$

$$H_{c2} = \frac{\Phi_0}{2\pi\xi^2} = \sqrt{2}\kappa H_c$$

#### The structure of the vortex lattice



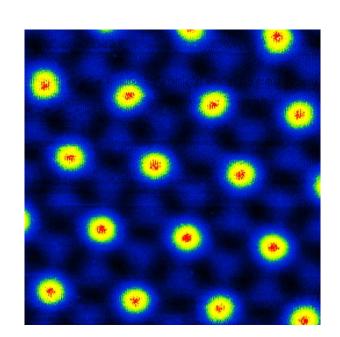
$$|\psi(r)| = \psi_{\infty} \tanh \frac{r}{\sqrt{2}\xi}$$
  $h(r) \approx \frac{\Phi_0}{2\pi\lambda^2} \left[ \ln \frac{\lambda}{r} + 0.12 \right]$ 



## From the solution of the linearized $1^{st}$ G-L equation at $H_{c2}$

$$\psi_L = \sum_n C_n \psi_n = \sum_n C_n \exp(inqy) \exp\left[-\frac{(x - x_n)^2}{2\xi^2}\right]$$

$$x_n = \frac{nq\Phi_0}{2\pi H}$$
 and  $C_n = C_{n+\nu}$ 



#### Interaction between vortices

In lecture 3, we found

$$\mathcal{E}_{\text{1-vortex}} \approx \frac{\Phi_{\text{0}}}{8\pi} h(0)$$

and in the case of 2 vortices

$$\varepsilon_{\text{2-vortices}} = \frac{\Phi_{\text{0}}}{8\pi} \left[ h_{\text{1}}(\mathbf{r}_{\text{1}}) + h_{\text{1}}(\mathbf{r}_{\text{2}}) + h_{\text{2}}(\mathbf{r}_{\text{1}}) + h_{\text{2}}(\mathbf{r}_{\text{2}}) \right]$$

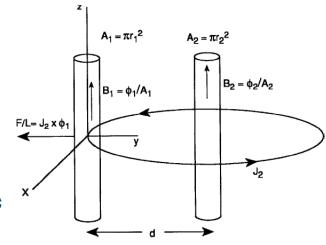
$$= 2 \left[ \frac{\Phi_0}{8\pi} h_1(r_1) \right] + \frac{\Phi_0}{4\pi} h_1(r_2)$$

$$=$$
 **2** $\varepsilon_{1-vortex} + \varepsilon_{interaction}$ 

#### Interaction between vortices

The force of vortex 1 on vortex 2 is

$$f_2 = -\nabla \varepsilon_{interaction} = J_1(r_2) \times \frac{\Phi_0}{c} \hat{z}$$



The obvious generalization to an arbitrary array is

$$f = J_s \times \frac{\Phi_0}{c} \hat{z}$$

 $J_s$  is the total supercurrent due to all other vortices  $J_{array}$  + any transport current  $J_{ext}$  at the vortex core position.

Obviously, at equilibrium

$$J_{array} \times \frac{\Phi_0}{c} \hat{z} = 0$$

#### Vortex motion and dissipation: Flux Flow

Let's focus on the effects of a transport current J<sub>ext</sub>

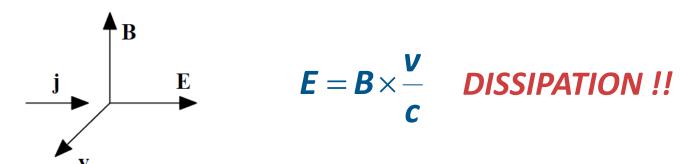
On a single vortex

$$f = J_{ext} \times \frac{\Phi_0}{c} \hat{z}$$

On the vortex lattice

$$F = \sum f = n_v f = J_{ext} \times n_v \frac{\Phi_0}{c} \hat{z} = J_{ext} \times \frac{B}{c}$$

Therefore, vortices tend to move transverse to  $J_{\rm ext}$ . If v is their velocity



#### Vortex motion and dissipation: Flux Flow

Bardeen and Stephen [PR 140 (1965) A1197] showed that the vortex velocity v is dumped by a viscous drag term

$$J_{ext} \frac{\Phi_0}{c} = \eta V_L$$

And

$$\rho_{ff} = \frac{E}{J} = B \frac{\Phi_0}{\eta c^2}$$

 $E = B \times \frac{V}{c}$ 

The following form is predicted for  $\eta$ 

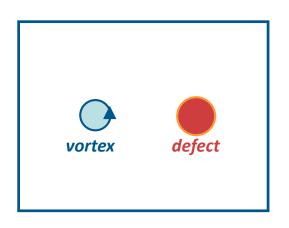
$$\eta = \frac{\Phi_0 B_{c2}}{\rho_n c^2}$$

**And thus** 

$$ho_{\mathit{ff}} = 
ho_{\mathit{n}} \left( \frac{B}{B_{c2}} \right)$$

Normal fraction in the SC, occupied by the vortex cores

#### **Vortex-defect interaction**



$$\Delta \textit{\textbf{G}} = \Delta \textit{\textbf{G}}_{\textit{condensation}} \big( \textit{\textbf{defect}} \big) + \Delta \textit{\textbf{G}}_{\textit{condensation}} \big( \textit{\textbf{vortex}} \big) - \Delta \textit{\textbf{G}}_{\textit{mag}}$$



$$\Delta G = \Delta G_{condensation} (defect) - \Delta G_{max}$$

Force to extract the vortex from the defect  $f_p = -\nabla U(r)$ 

Defects are impurities, grain boundaries and any spatial inhomogeneity, whose size is comparable with  $\lambda$  and  $\xi$ 

#### **Vortex-defect interaction**

$$f = J_{ext} imes \frac{\Phi_0}{c}$$

Force exerted from  $J_{ext}$ 

$$\boldsymbol{f_p} = \boldsymbol{J_c} \times \frac{\Phi_0}{\boldsymbol{c}}$$

Pinning Force exerted from defects

*J<sub>c</sub>* is the critical current density

If 
$$f < f_p$$
 then  $v = 0$  and  $\rho = 0$ 

If 
$$f > f_p$$
 then  $\mathbf{v} \neq \mathbf{0}$  and  $\rho \neq \mathbf{0}$ 

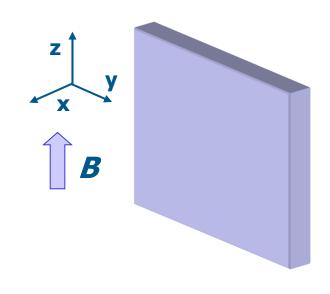
Only superconductors with defects are truly superconducting (  $\rho$  = 0 ) !!

#### Critical state: the Bean model

$$F = J \times \frac{B}{c} + \nabla \times H = \frac{4\pi}{c}J$$

For an infinite slab in parallel field

$$F = \frac{JB}{c} = \frac{1}{4\pi}B\frac{dB}{dx} \leq F_P = \frac{J_cB}{c}$$

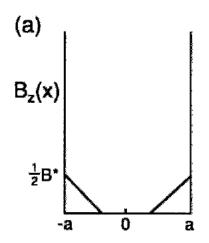


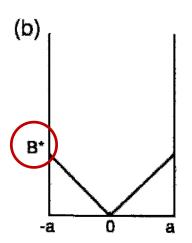
In the critical state 
$$\mathbf{F} = \mathbf{F}_p \Rightarrow \frac{d\mathbf{B}}{d\mathbf{x}} = \frac{4\pi}{c} \mathbf{J}_c \Rightarrow \Phi_0 \frac{d\mathbf{n}_v}{d\mathbf{x}} = \frac{4\pi}{c} \mathbf{J}_c$$

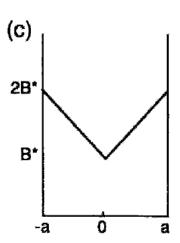
**N.B.** The critical current density  $J_c$  is different from the depairing current  $J_d$ 

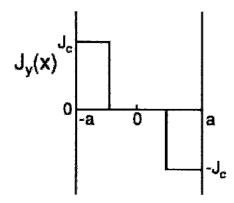
Depairing current 
$$\frac{1}{2}n_s m^* v_d^2 = \frac{2\pi}{c^2} \lambda^2 J_d^2 = \frac{H_c^2}{8\pi} \Rightarrow J_d = c \frac{H_c}{4\pi\lambda}$$

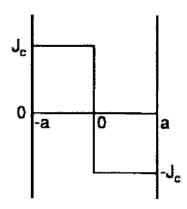
#### Critical state: the Bean model

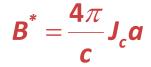


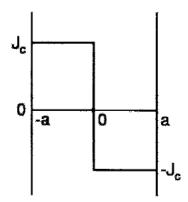




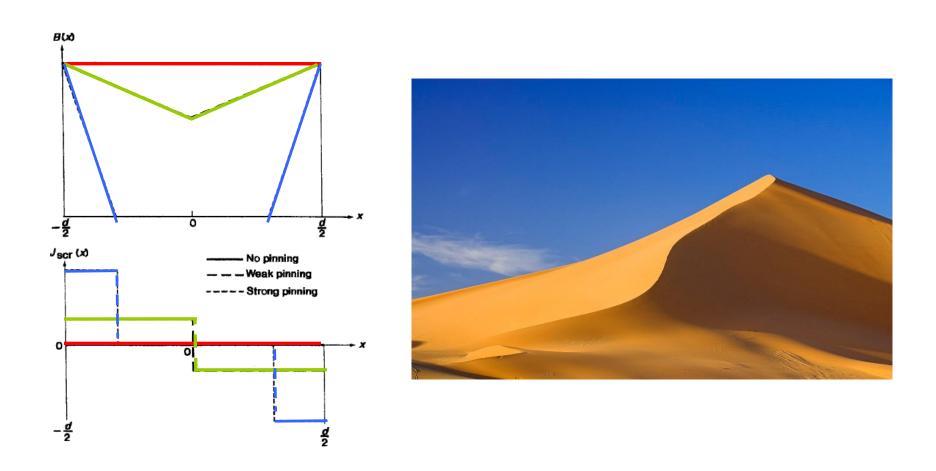






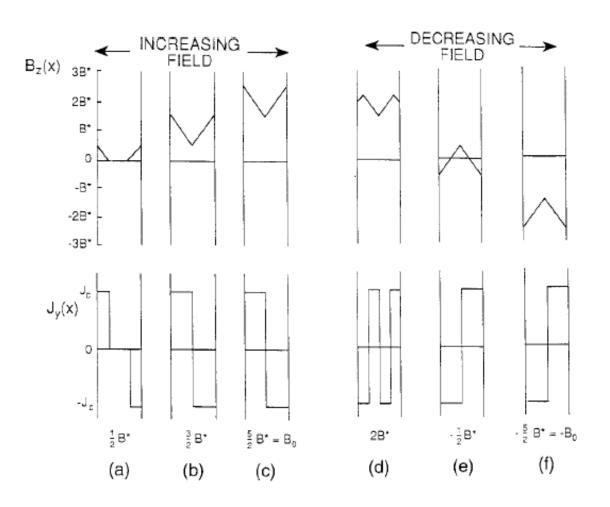


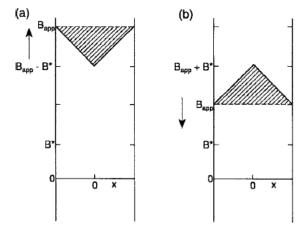
#### Critical state: Pinning strength



The critical current density  $J_c$  depends on the type, size and distribution of the pinning centers

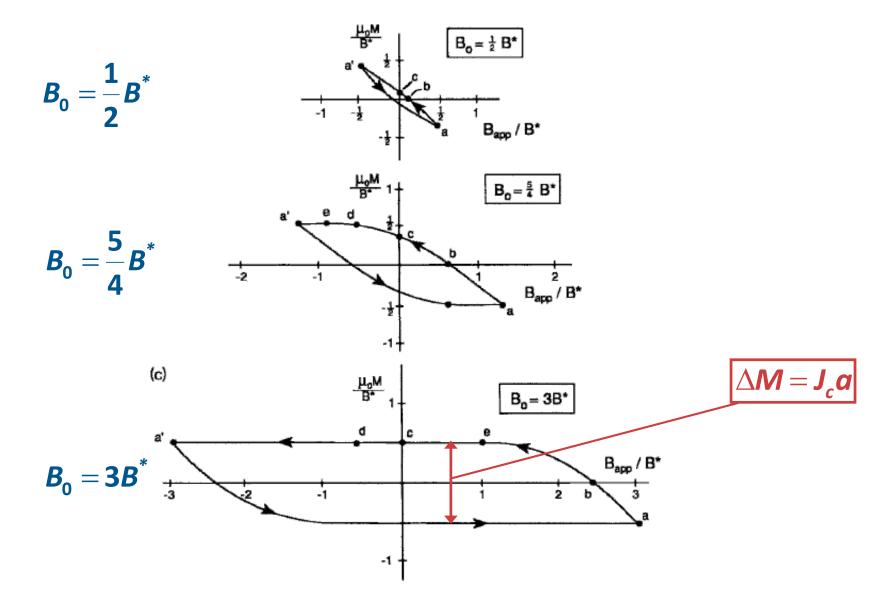
#### Critical state: Reversing field



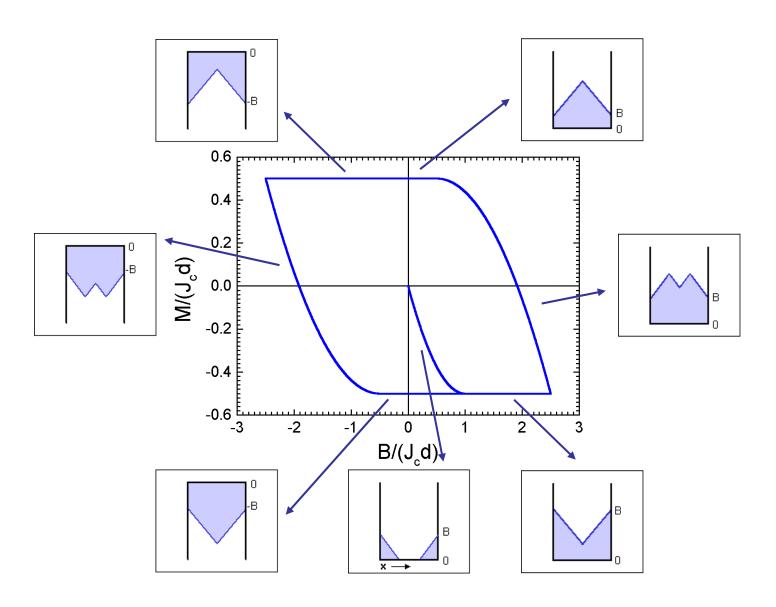


The shaded area corresponds to the sample magnetization

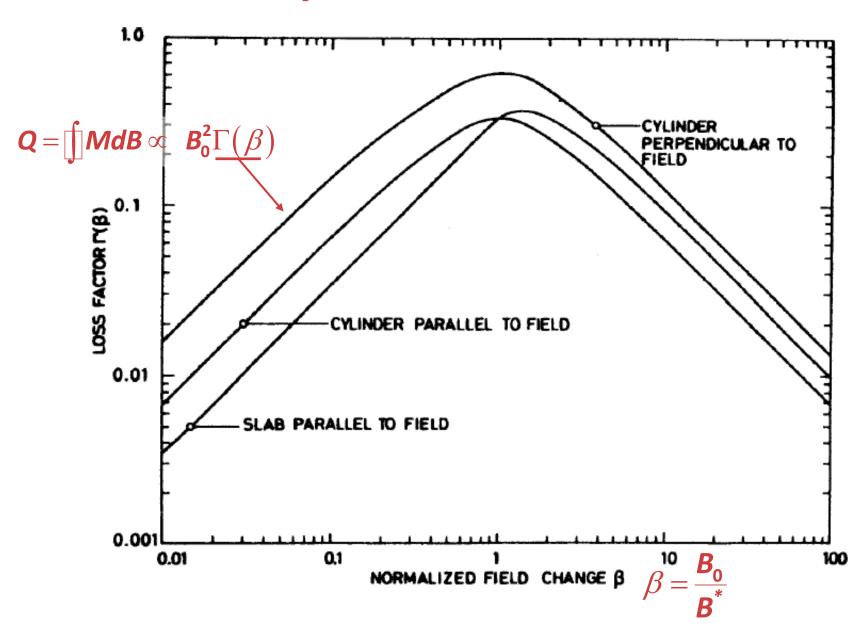
#### Critical state: Hysteresis loop



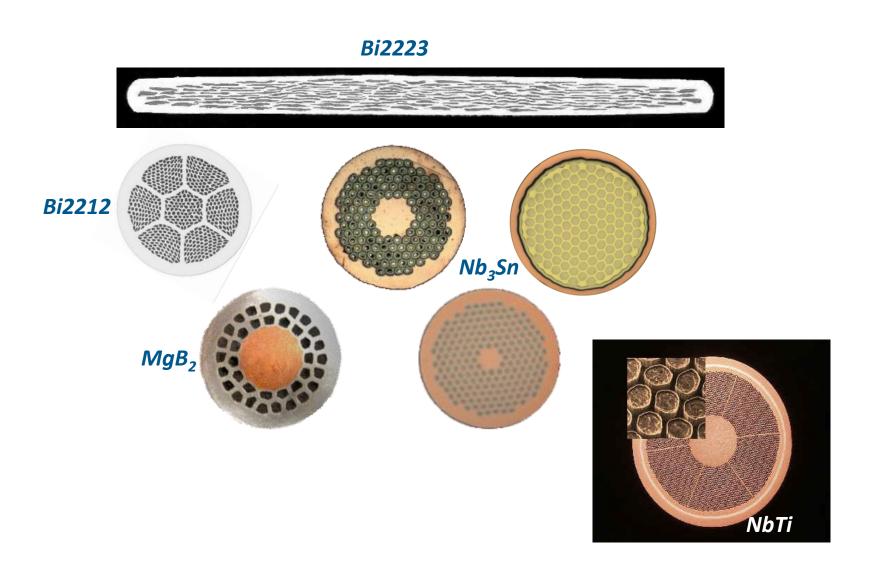
## Critical state: Hysteresis loop



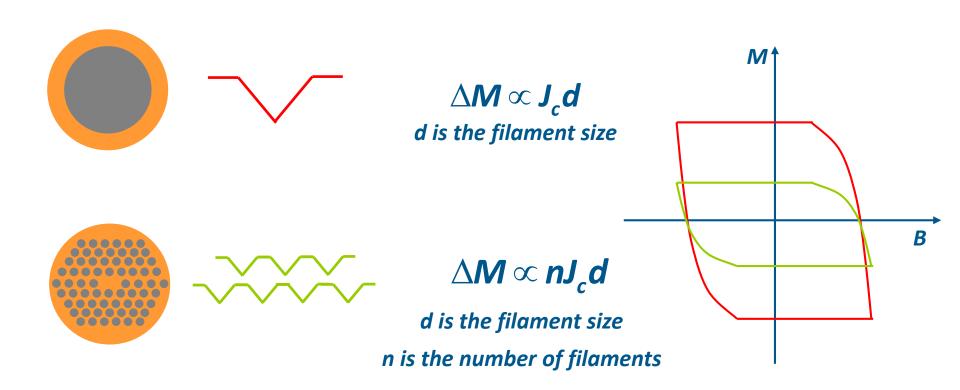
#### Critical state: Hysteresis and losses



## Superconducting wires are multifilamentary. WHY?



#### Superconducting wires are multifilamentary. WHY?



With the subdivision of the superconducting layer in filaments, hysteretic losses are reduced but the critical current density  $J_c$  is unchanged

## Extracting J<sub>c</sub> from magnetization

Knowing that  $M = \frac{1}{2V_V} \int_V r \times J \, dV$  it is possible to calculate the expression of M for a given, constant J

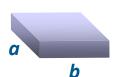
$$J_c = 3 \frac{\Delta M}{R}$$

$$J_c = 2\frac{\Delta M}{d}$$

$$J_c = \frac{3}{2} \frac{\Delta M}{R}$$

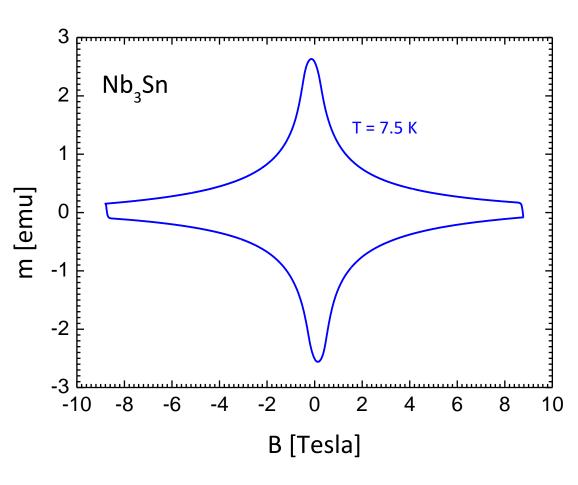
$$J_c = 3 \frac{\Delta M}{b(3-b/a)}$$

$$J_c = \frac{3\pi}{8} \frac{\Delta M}{R}$$



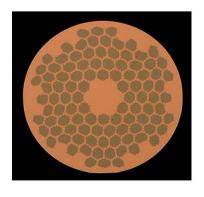


## Field dependence of J<sub>c</sub>



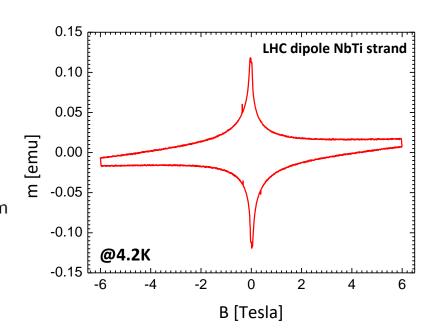
$$\Delta \mathbf{M} = \Delta \mathbf{M}(\mathbf{B}) \implies \mathbf{J}_{c} = \mathbf{J}_{c}(\mathbf{B})$$

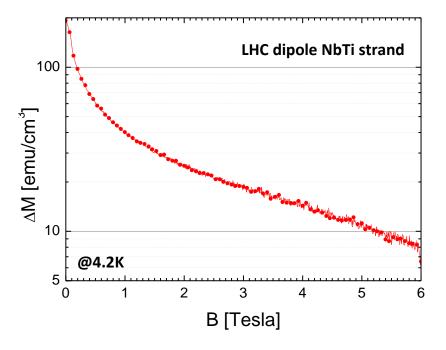
## Field dependence of J<sub>c</sub>

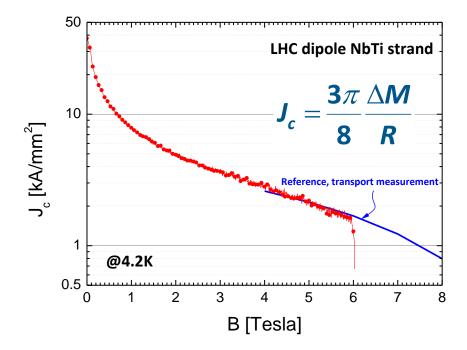


#### LHC dipole strand

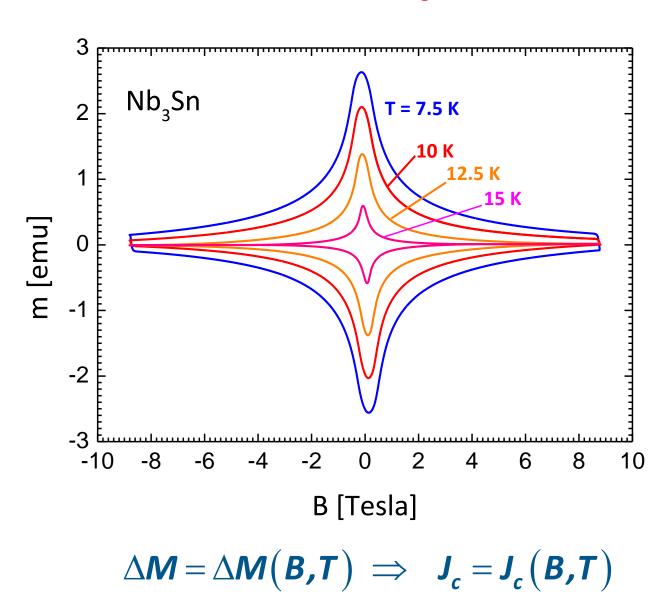
- F8670 Ø 1.065 mm
- Cu : NbTi = 1.65
- Filament diameter  $\approx$  7  $\mu m$
- Ic = 540 A @ 7 T; 4.2 K





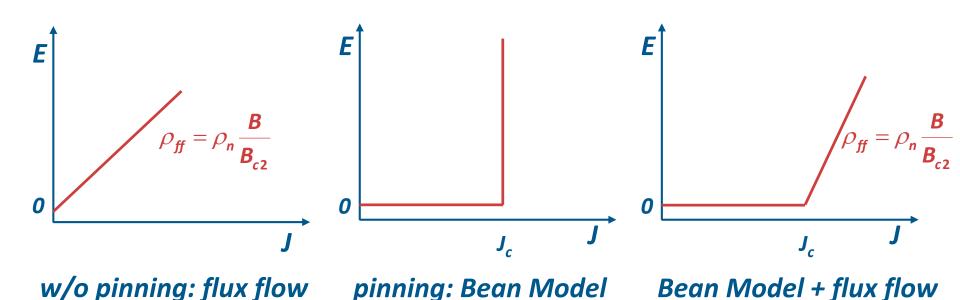


## Temperature dependence of J<sub>c</sub>



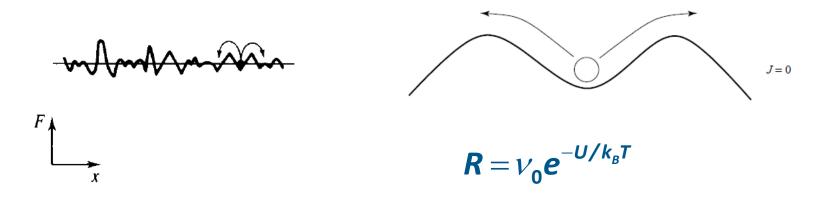
#### E-J relation for a type-II superconductor

E-J relation for a superconductor in the mixed state

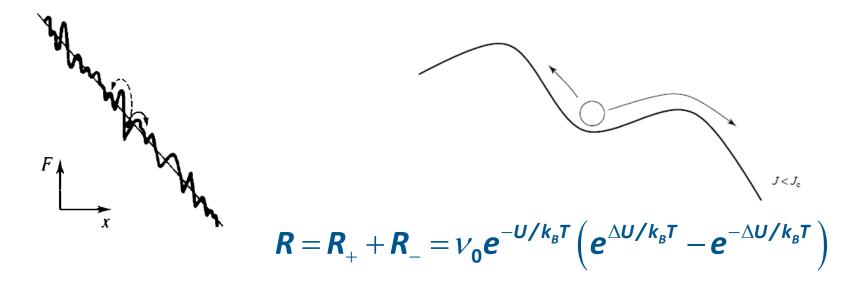


The effect of thermal excitation was not yet included

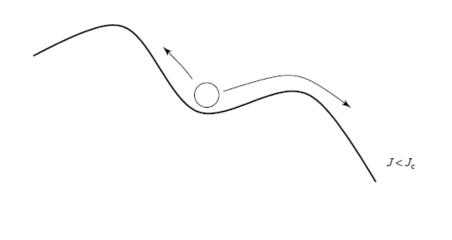
#### Beyond Bean: Thermally activated flux creep



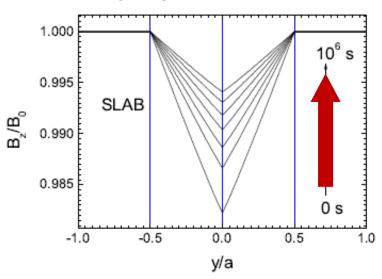
#### In the presence of an external current



#### Thermally activated flux creep



#### The B-profile relaxes with t



$$\mathbf{R} = \mathbf{R}_{+} + \mathbf{R}_{-} = v_{0} \mathbf{e}^{-U/k_{B}T} \left( \mathbf{e}^{\Delta U/k_{B}T} - \mathbf{e}^{-\Delta U/k_{B}T} \right)$$

In a first approximation

$$R \approx R_{+} = v_{0}e^{-(U-\Delta U)/k_{B}T}$$
 where  $\Delta U = \Delta U(J)$ 

#### Thermally activated flux creep

$$\mathbf{R} \approx \mathbf{R}_{+} = v_{0} e^{-\left[\mathbf{U} - \Delta \mathbf{U}(\mathbf{J})\right]/k_{B}T} \Rightarrow v = v_{0} \exp\left[-\frac{U(\mathbf{J})}{k_{B}T}\right]$$

*In the infinite slab – parallel field geometry* 

$$\boxed{\frac{\partial \mathbf{E}}{\partial \mathbf{x}} = \frac{\partial \mathbf{B}}{\partial \mathbf{t}}} \quad + \quad \boxed{\mathbf{E} = \mathbf{v}\mathbf{B}} \quad \Rightarrow \quad \frac{\partial B}{\partial t} = \frac{\partial}{\partial x}(vB)$$

$$\frac{\partial B}{\partial x} = -\mu_0 J$$
 with  $B\|z$  and  $J\|y$   $\Rightarrow$   $\frac{\partial J}{\partial t} = -\frac{1}{\mu_0} \frac{\partial^2}{\partial x^2} (vB)$ 

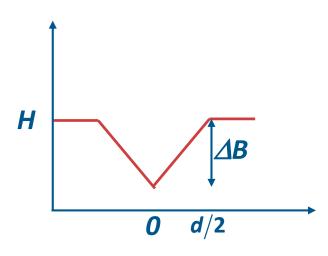
$$\frac{\partial J}{\partial t} = -\frac{1}{\mu_0} \frac{\partial^2}{\partial x^2} \left[ v_0 e^{-\frac{U(J)}{k_B T}} B \right]$$

## Thermally activated flux creep: Anderson-Kim model

$$\iint \frac{\partial J}{\partial t} = \iint \frac{1}{\mu_0} \frac{\partial^2}{\partial x^2} \left[ v_0 e^{-\frac{U(J)}{k_B T}} B \right]$$

- 1) ∆B << H
- 2) J is constant in space

$$\frac{\partial J}{\partial t} = -\frac{8v_0 H}{\mu_0 d^2} \exp\left[-\frac{U(J)}{k_B T}\right]$$



In the Anderson-Kim model 
$$U = U_0 \left( 1 - \frac{J}{J_0} \right)$$
 where  $U_0 = U_0 \left( B, T \right)$ 

The solution for J is 
$$J(t) = J_0 \left[ 1 - \frac{k_B T}{U_0} ln \left( \frac{t}{t_0} \right) \right]$$

#### Thermally activated flux creep: Anderson-Kim model

The current density J and the magnetization M both relax with the logarithm of time

 $M \propto J$ 

$$J(t) = J_0 \left[ 1 - \frac{k_B T}{U_0} ln \left( \frac{t}{t_0} \right) \right]$$

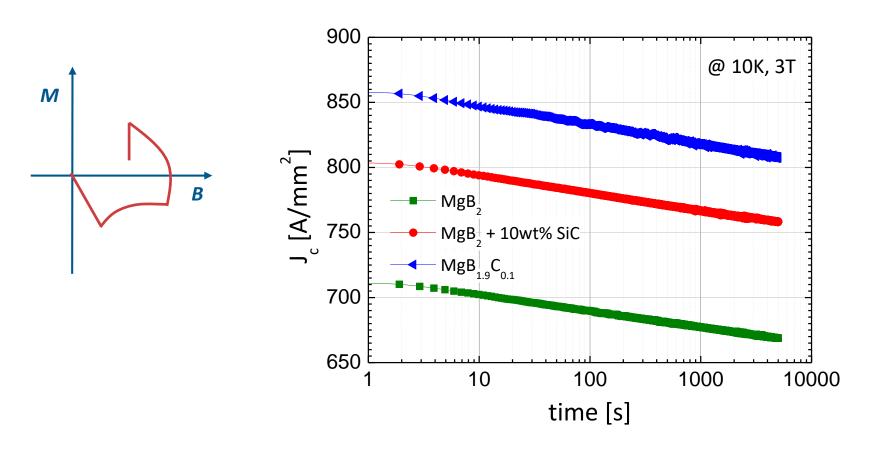
The relaxation rate S is directly proportional to T and inversely proportional to  $U_0$ 

$$S = -\frac{1}{M_0} \frac{dM}{d \ln t} = \frac{k_B T}{U_0}$$

Measuring S as a function of B and T, we have an experimental access to the pinning energy

$$U_0 = U_0(B,T)$$

#### Magnetic relaxation experiments



Typical values of the activation energy  $U_0$  span in the range 10-100 meV (~100-1000 K)

## **Bibliography**

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Chapter 5

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